# IF detector IC for 900MHz spread spectrum cordless phones BH4127FV

The BH4127FV is a mixer, IF amplifier, and FM detector IC developed for use with 900MHz spread spectrum cordless phones

# Applications

900MHz spread spectrum cordless phones

### Features

- Built-in mixer circuit, IF circuit, RSSI circuit, and FM detector circuit.
- Operates at mixer input frequencies ranging from 20 to 300 MHz.
- 3) Equipped with a battery save function.
- 4) FM detector circuit demodulates up to ±750kHzdev.
- 5) FM detector circuit demodulates up to 2.6Mbps.

# ● Absolute maximum ratings (Ta = 25°C, with the measurement circuit)

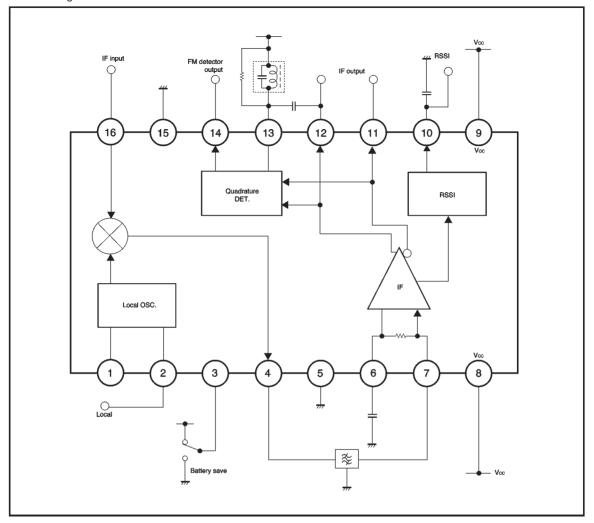
Parameter	Symbol	Limits	Unit
Power supply voltage	Vcc	7.0	٧
Power dissipation	P□	350*	mW
Storage temperature	Tstg	<b>−55∼</b> +125	°C

<sup>\*</sup> Reduced by 3.5mW for each increase in Ta of 1℃ over 25℃.

# Recommended operating conditions

Parameter	Symbol	Limits	Unit
Power supply voltage	Vcc	2.3~5.5	V
Operating temperature	Topr	<b>−40</b> ~+85	°

# ●Block diagram



# Pin descriptions

Pin No.	Function	Internal peripheral circuit	DC voltage(V)
1	Local oscillator pin (base)  Connect crystal resonator and capacitor	Vcc Vcc Vcc Vcc	Vcc-0.6
2	Local oscillator pin (emitter)  Connect crystal resonator or inject from external capacitor	1 To MIXER	Vcc
3	Battery save pin  Pin 3 voltage≦ 0.2V: Battery save  2V ≦ pin 3 voltage ≦ Vcc: Active	30k	_
4	Mixer output pin  Connect ceramic filter  Output impedance: 330 Ω	4 270 Voc	V∞-1.5
5	Ground pin	GND for IF stage and FM detection stage	GND
6	IF amplifier bypass pin  Connect capacitor	Vcc → ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★ ★	Vcc
7	IF amplifier input pin  Connect ceramic filter Input impedance: 330 Ω	7	Vcc
8	Vcc pin 1	Vcc for MIX stage and IF early stage	Vcc
9	Vcc pin 2	Vcc for IF later stage and FM detection stage	Vcc

Pin No.	Function	Internal peripheral circuit	DC voltage (V)
10	RSSI output pin  Connect capacitor	10 Vcc	0.1
11 12	IF amplifier output pin Pins 11 and 12 are opposite-phase output	100 Vcc	Vcc-1
13	Discriminator pin  Connect phase shift coil or ceramic discriminator	500 Vcc	Vcc
14	FM demodulated signal output pin Output impedance is $360\Omega$	330 14	0.9
15	Ground pin	GND for MIX stage	GND
16	Mixer pin  Connect first IF signal from DC cutoff	2.4k Vcc	1.0

•Electrical characteristics (unless otherwise noted, Ta = 25°C, Vcc = 3.0V) Signal source: f<sub>IN (MIX)</sub> = 254.4MHz, f<sub>IN (LO)</sub> = 243.2MHz, 100dBμV, f<sub>IN (IF)</sub> = 11.2MHz AC level to be indicated by termination

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Quiescent current	lα	4.4	5.5	6.6	mA	With local oscillation OFF	
Current during battery save	IQ(BS)	-	0	5	μΑ	_	
Dathara faration in the same	Vтн-н	2	_	Vcc	٧	Active	
Battery save function input voltage	V <sub>TH</sub> -L	GND	_	0.2	٧	Battery save	
⟨MIX—oscillator⟩	⟨MIX—oscillator⟩						
Mixer operating frequency	fмıx	20	_	300	MHz	_	
Mixer conversion gain	Gvc	16	20	24	dB	V <sub>IN(MIX)</sub> =60dB μV	
-1dB compression output level	Vом	_	103	_	dB μV	_	
3rd order intercept point	IP₃	_	110	_	dB μV	f1=248.75MHz, f2=249.05MHz	
Noise index	NF	_	9.7	_	dB	LC matching input	
Mixer input admittance	YIN(MIX)	_	1.25+j7.47	_	ms	f=250MHz	
Mixer output resistance	<b>R</b> o(міх)	_	330	_	Ω	_	
Local oscillator operating frequency	fLO	20	_	120	MHz	_	
Local input level	VIN(LO)	95	100	105	dB μV	_	
Local input admittance	YIN(LO)	_	1.36+j9.72	_	ms	f=250MHz	
⟨IF section⟩							
IF operating frequency	fır	4	_	15	MHz	_	
IF amplifier gain	Gv	_	75	_	dB	_	
IF input resistance	RIN(IF)	_	330	_	Ω	_	
IF output level	Voif	0.4	0.5	0.6	V <sub>P-P</sub>	$V_{IN(IF)}$ =80dB $\mu$ V	
IF output duty ratio	DR	40	50	60	%	V <sub>IN(IF)</sub> =80dB μ V, C <sub>L</sub> =10pF	
⟨RSSI section⟩		•					
Output voltage 1	VRSSI1	-	0.15	0.4	٧	No input	
Output voltage 2	VRSSI2	1.0	1.2	1.4	٧	$V_{IN(IF)}=70$ dB $\mu$ V	
Output voltage 3	VRSSI3	1.8	2.0	2.2	٧	$V_{IN(IF)}=100dB \mu V$	
Dynamic range	DR	_	70	_	dB	_	
Output resistance	Ro(RSSI)	12	15	18	kΩ	_	
Rise time at power on	Ton	-	20	_	μs	CL=100pF, VIN(MIX)=60dB μV	
Fall time at power off	Toff	-	5	_	μs	CL=100pF, VIN(MIX)=60dB μ V	
RSSI rise time	TR	_	9	_	μS	CL=100pF, VIN(MIX)=60dB μV	
RSSI fall time	TF	_	11	_	μS	CL=100pF, VIN(MIX)=60dB μ V	

Signal source:  $f_{\text{IN (IF)}}$  = 11.2MHz,  $\Delta f$  =  $\pm 100 \text{kHz}$  dev, fm = 1kHz AC level to be indicated by termination

Parameter	Symbol	Min.	Тур.	Мах.	Unit	Conditions	
⟨Detector section⟩							
Detection sensitivity	SDET	_	1.243	_	mV / kHz	$V_{IN (IF)} = 80 dB \mu V$	
Detection output level	Vo	63	87	120	mV <sub>rms</sub>	V <sub>IN (IF)</sub> =80dB μ V	
Detection frequency	fdet	_	1.3	_	MHz	$V_{IN (IF)} = 80 dB \mu V$	
12dB SINAD sensitivity	S (12dB)	12	16	20	dΒμV		
S / N ratio	S/N	_	70	_	dB	$V_{IN (IF)} = 80 dB \mu V$	
AM rejection ratio	AMR	_	60	_	dB	$V_{IN (IF)} = 80 dB \mu V, AM = 30\%$	

# Measurement circuit

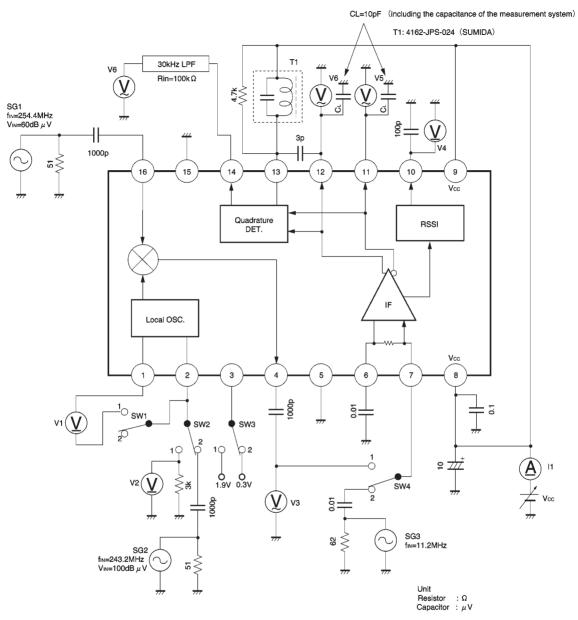


Fig.1

# Application example

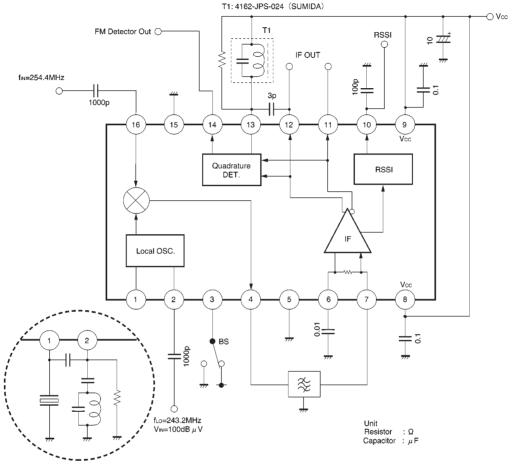
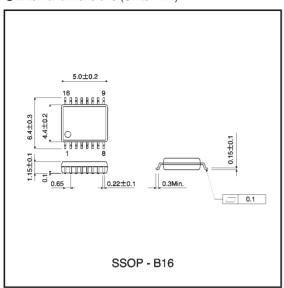


Fig.2

●External dimensions (Units: mm)



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